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	Docket: YOR920020182	US2 (15790A)			****
Re:	Hussein I. Hanafi et al. U.S. Patent Appin. No. 1	0/659,949	CC:		
Phone			Date:	10/5/2005	
Fax	571-273-8300	1	Pages:	8 pages including	fax cover
To:	Art Unit:2823		From:	Leslie S. Szivos	

### PATENT OFFICE DATE STAMP WILL ACKNOWLEDGE RECEIPT OF:

- 1. Transmittal of Information Disclosure Statement (in duplicate)
- 2. Information Disclosure Statement (w/Form PTO-1449)
- 3. Certificate of transmission by facsimile dated October 5, 2005
- 5. Authorization to charge IBM deposit account

If you have any questions concerning this facsimile please contact Vivian Henriquez at 516-742-4343. Thank you

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TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT (Under 37 CFR 1.97(b) or 1.97(c))					Docket No. YOR920020182US2				
In Re A	n Re Application Of: Hussein I. Hanafi et al.								
Applic	Application No. Filing Date Examiner Customer No. Group Art Unit Confirmation No.								
	10/659,949 September 11, 2003 Fernando L. Toledo 23389 2823 5877								
	Title: LOW RESISTANCE T-GATE MOSFET DEVICE USING A DAMASCENE GATE PROCESS AND AN INNOVATION OXIDE REMOVAL ETCH								
			Address to: Commissioner for Patent P.O. Box 1450 Alexandria, VA 22313-145			·			
_			37 CFR 1.97(b)						
ī. Z	1. The Information Disclosure Statement submitted herewith is being filed within three months of the filing of a national application other than a continued prosecution application under 37 CFR 1.53(d); within three months of the date of entry of the national stage as set forth in 37 CFR 1.491 in an international application; before the mailing of a first Office Action on the merits, or before the mailing of a first Office Action after the filing of a request for continued examination under 37 CFR 1.114.								
			37 CFR 1.97(c)						
2.	2. The Information Disclosure Statement submitted herewith is being filed after the period specified in 37 CFR 1.97(b), provided that the Information Disclosure Statement is filed before the mailing date of a Final Action under 37 CFR 1.113, a Notice of Allowance under 37 CFR 1.311, or an Action that otherwise closes prosecution in the application, and is accompanied by one of:								
	☐ the s	statement specified in	37 CFR 1.97(e);						
			OR						
	☐ the f	ee set forth in 37 CF	R 1.17(p).						
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Title: LOW RESISTANCE T-GATE MOSFET DEVICE USING A DAMASCENE GATE PROCESS AND AN INNOVATION OXIDE REMOVAL ETCH								
Payment of Fee  (Only complete if Applicant elects to pay the fee set forth in 37 CFR 1.17(p))  A check in the amount of is attached.  The Director is hereby authorized to charge and credit Deposit Account No. as described below.  Charge the amount of Credit any overpayment.  Charge any additional fee required.  Payment by credit card. Form PTO-2038 is attached.  WARNING: Information on this form may become public. Credit card information should not be included on this form. Provide credit card information and authorization on PTO-2038.  Certificate of Transmission by Facsimile*  Certificate of Mailing by First Class Mail  I certify that this document and authorization to charge deposit account is being facsimile transmitted to the United States Patent and Trademark Office (Fax 571-273-8300)  October 5, 2005  (Date)  Leslie S. Szivos, Ph.D.  Signature  Leslie S. Szivos, Ph.D.								
*This certificate may only be used if paying by deposit account.  Dated: October 5, 2005  Eignature  Leslie S. Szivos, Ph.D. Registration No. 39,394  SCULLY, SCOTT, MURPHY & PRESSER  400 Garden City Plaza - Suite 300  Garden City, New York 11530								
x <del>c</del> :								

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2.	<ul> <li>2.          The Information Disclosure Statement submitted herewith is being filed after the period specified in 37 CFR 1.97(b), provided that the Information Disclosure Statement is filed before the mailing date of a Final Action under 37 CFR 1.113, a Notice of Allowance under 37 CFR 1.311, or an Action that otherwise closes prosecution in the application, and is accompanied by one of:     </li> </ul>										
	☐ the s	statement specified in	37 CFR 1.97(e);								
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	☐ the f	ee set forth in 37 CFF	R 1.17(p).								
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TRANSMITTAL OF INFORMATION DISCLOSURE STATEMENT (Under 37 CFR 1.97(b) or 1.97(c))					Docket No. YOR920020182US2			
In Re Application o	f: Hussein I. Hans	afi et al.						
Application No. Filing Date Examiner Customer No. Group Art Unit Confirmation No.								
10/659,949	September 11, 2003	Fernando L.	Toledo	23389	2823	5877		
	STANCE T-GATE M NOVATION OXIDE	E REMOVAL ETCI		MASCENE GA	TE PROCESS			
		nplete if Applicant ele	cts to pay the f	ee set forth in 37	CFR 1.17(p))			
□ A check in the amount of is attached.  □ The Director is hereby authorized to charge and credit Deposit Account No. as described below.  □ Charge the amount of □ Credit any overpayment. □ Charge any additional fee required. □ Payment by credit card. Form PTO-2038 is attached.  WARNING: Information on this form may become public. Credit card information should not be included on this form. Provide credit card information and authorization on PTO-2038.  Certificate of Transmission by Facsimile*  □ Certificate of Mailing by First Class Mail □ Certify that this document and authorization to charge deposited account is being facsimile transmitted to the United States Patent and Trademark Office (Fax 571-273-8300) □ Ctober 5, 2005 □ Commissiones for Patents, P.O. Box 1450, All candida, VA 22313-1450 [37 SER 1.8(a)] on □ (Date) □ Signature □ Remarked of Person Mailing Correspondence								
Leslie S. Szivos,  Typed or P	rinted Name of Person Sign	ning OP tificate	Туре	d or Printed Name o	of Person Mailing Ce	rtificate		
Leslie S. Szivos, Ph.I Registration No. 39,	394 MURPHY & PRESSI 1za - Suite 300		Dated: C	October 5, 2005				
cc:	•							

### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Hussein I. Hanafi et al.

Examiner: Fernando L. Toledo

Serial No:

10/659,949

Art Unit: 2823

Dated: October 5, 2005

Filed:

September 11, 2003

**Docket:** YOR920020182US2 (15790A)

For: LOW RESISTANCE T-GATE MOSFET

DEVICE USING A DAMASCENE GATE

PROCESS AND AN INNOVATION

OXIDE REMOVAL ETCH

Confirmation No. 5877

Mailstop Amendment Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

### INFORMATION DISCLOSURE STATEMENT

Sir:

In accordance with 37 C.F.R. §§ 1.97 and 1.98, it is requested that the following references, which are also listed on the attached Form PTO-1449, be made of record in the above-identified case.

1. United States Patent 6,271,094 B1, dated August 7, 2001, issued to Boyd et al.

#### **CERTIFICATE OF MAILING UNDER 37 C.F.R. §1.8(a)**

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on October 5, 2005

Dated: October 5, 2005

Leslie &. Szivos, Ph.D.

Consideration of this Information Disclosure Statement is respectfully requested, since the art provided may be material to the examination of the present application as defined under 37 C.F.R. §1.56.

Inasmuch as this Information Disclosure Statement is being submitted in accordance with the schedule set out in 37 C.F.R. § 1.97(b), no statement or fee is required.

Respectfully submitted,

Leslie S. Szivos

Registration No. 39,394

Scully, Scott, Murphy & Presser 400 Garden City Plaza – Suite 300 Garden City, New York 11530 (516) 742-4343

LSS:vh

INFORMATION DISCLOSURE CITATION				Docket Number (Optional)	Application Number				
				YOR920020182US2 (15790A) 10/659,949 Applicant(s)					
		(Use several sheets if necessa		Hussein I. Hanafi et al.  Filing Date Group Art Unit					
					September 11, 2003			2823	
			U.S	. PATENT	DOCUMENTS	<u> </u>			
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		6,271,094 B1	8/7/2001	Boyd et	al.				
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Form PTO-A820

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